

Part number	Manufacturer	Device name
ADS		
RT1N141M	Isahaya Electronics Corporation	BRT (Bias Resistor Transistor)
PDZVTR13B	ROHM Co., Ltd.	Zener diode
PDZVTR15B	ROHM Co., Ltd.	Zener diode
RGCL60TS60D	ROHM Co., Ltd.	IGBT
2SC2412K	ROHM Co., Ltd.	BJT
2SA2142	Toshiba Corporation	BJT
2SB1198K	ROHM Co., Ltd.	BJT
LTspice		
3000GXHH32	Toshiba Corporation	Rectifier diode
ST2000GXH32	Toshiba Corporation	IGBT
ST3000GXH35A	Toshiba Corporation	IGBT
TC75S102F	Toshiba Corporation	OpAmp
TCK22891G	Toshiba Corporation	Gate driver
TLP155E	Toshiba Corporation	Photocoupler
TLP241BP	Toshiba Corporation	Photorelay
TLP294-4	Toshiba Corporation	Photocoupler
TLP295-4	Toshiba Corporation	Photocoupler
TLP5784H	Toshiba Corporation	Photocoupler
TLP620M	Toshiba Corporation	Photocoupler
TLX9309	Toshiba Corporation	Photocoupler
TPD2015FN	Toshiba Corporation	Intelligent power device
TPD2017FN	Toshiba Corporation	Intelligent power device
PSPice		
CL05C8R2DB51PN	SAMSUNG ELECTRO-MECHANICS,	Ceramic capacitor
DAN202FMFH	ROHM Co., Ltd.	Switching diode
EEEHBC101UAP	Panasonic Corporation	Aluminum electrolytic capacitor
HBO471M1ETT	Leon Electronics	Aluminum electrolytic capacitor
LTC4359HMS8	Analog Devices Inc.	Gate driver
RP111N001D	Nisshinbo Micro Devices Inc.	LDO (Low Drop Out)
BAS21L	ON Semiconductor.	Switching diode
BZX84-B20	Nexperia B.V.	Zener diode
BZX84-C15	Nexperia B.V.	Zener diode
2SK208	Toshiba Corporation	JFET
BLM18KG101TH1	Murata Manufacturing Co., Ltd.	Ferrite beads
BCW66G	Nexperia B.V.	BJT
RP111N331D	Nisshinbo Micro Devices Inc.	LDO (Low Drop Out)